## NSN 5961-01-300-8295

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
16.51 millimeters
Terminal Length:
14.73 millimeters
Overall Height:
4.82 millimeters
Overall Width:
10.66 millimeters
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-220ab
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal and unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
8.00 amperes forward current, total rms pascal
Maximum Operating Tempurature Per Measurement Point:
110.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 pin
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0